# **MOSFET** – N-Channel, Small Signal, SOT-23

60 V, 115 mA

# 2N7002L, 2V7002L

### Features

- 2V Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC–Q101 Qualified and PPAP Capable (2V7002L)
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant



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V <sub>(BR)DSS</sub>	R <sub>DS(on)</sub> MAX	I <sub>D</sub> MAX
60 V	7.5 Ω @ 10 V, 500 mA	115 mA

N-Channel

3

## MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Drain-Source Voltage	V <sub>DSS</sub>	60	Vdc
Drain-Gate Voltage ( $R_{GS}$ = 1.0 M $\Omega$ )	V <sub>DGR</sub>	60	Vdc
Drain Current – Continuous T <sub>C</sub> = 25°C (Note 1) T <sub>C</sub> = 100°C (Note 1) – Pulsed (Note 2)	I <sub>D</sub> I <sub>D</sub> I <sub>DM</sub>	±115 ±75 ±800	mAdc
Gate–Source Voltage – Continuous – Non–repetitive (t <sub>p</sub> ≤ 50 μs)	V <sub>GS</sub> V <sub>GSM</sub>	±20 ±40	Vdc Vpk

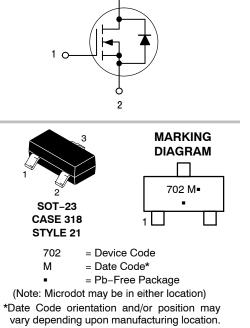
### THERMAL CHARACTERISTICS

Characteristic	Symbol	Мах	Unit
Total Device Dissipation FR–5 Board (Note 3) T <sub>A</sub> = 25°C Derate above 25°C Thermal Resistance, Junction–to–Ambient	P <sub>D</sub> R <sub>θJA</sub>	225 1.8 556	mW mW/°C °C/W
Total Device Dissipation (Note 4) Alumina Substrate, T <sub>A</sub> = 25°C Derate above 25°C Thermal Resistance, Junction-to-Ambient	P <sub>D</sub> R <sub>θJA</sub>	300 2.4 417	mW mW/°C °C/W
Junction and Storage Temperature	T <sub>J</sub> , T <sub>stg</sub>	–55 to +150	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

 The Power Dissipation of the package may result in a lower continuous drain current.

- 2. Pulse Test: Pulse Width  $\leq$  300  $\mu$ s, Duty Cycle  $\leq$  2.0%.
- 3. FR-5 = 1.0 x 0.75 x 0.062 in.
- 4. Alumina = 0.4 x 0.3 x 0.025 in 99.5% alumina.



### **ORDERING INFORMATION**

Device	Package	Shipping <sup>†</sup>	
2N7002LT1G		3,000 Tape & Reel	
2N7002LT3G	SOT-23 (Pb-Free)	1 10 000 Jane & Reel	
2N7002LT7G		3,500 Tape & Reel	
2V7002LT1G		3,000 Tape & Reel	
2V7002LT3G	SOT-23 (Pb-Free)	10,000 Tape & Reel	
2N7002LT1H*		3,000 Tape & Reel	
2N7002LT7H*		3,500 Tape & Reel	

+For information on tape and reel specifications,

including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

\*Not for new design.

# 2N7002L, 2V7002L

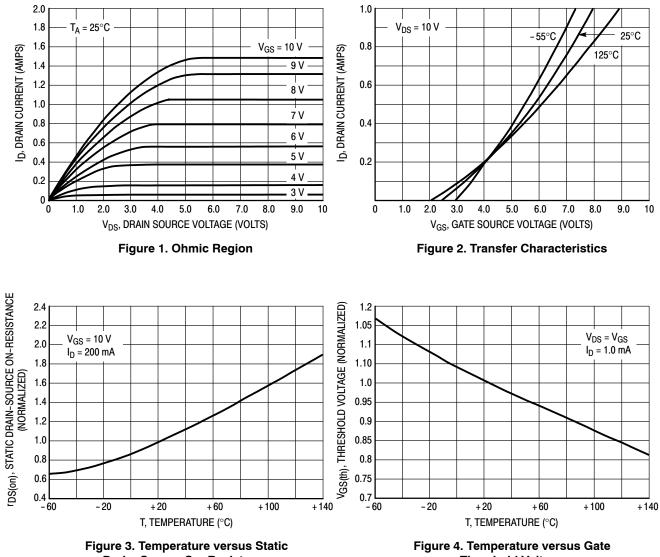
# **ELECTRICAL CHARACTERISTICS** ( $T_A = 25^{\circ}C$ unless otherwise noted)

Characteristic	Symbol	Min	Тур	Мах	Unit
OFF CHARACTERISTICS			•		
Drain–Source Breakdown Voltage ( $V_{GS}$ = 0, $I_D$ = 10 µAdc)	V <sub>(BR)DSS</sub>	60	-	-	Vdc
$ \begin{array}{ll} \mbox{Zero Gate Voltage Drain Current} & T_J = 25^\circ C \\ (V_{GS} = 0,  V_{DS} = 60  Vdc) & T_J = 125^\circ C \end{array} $	I <sub>DSS</sub>	-		1.0 500	μAdc
Gate-Body Leakage Current, Forward (V <sub>GS</sub> = 20 Vdc)	I <sub>GSSF</sub>	-	_	100	nAdc
Gate-Body Leakage Current, Reverse (V <sub>GS</sub> = -20 Vdc)	I <sub>GSSR</sub>	-	_	-100	nAdc
ON CHARACTERISTICS (Note 5)					
Gate Threshold Voltage $(V_{DS} = V_{GS}, I_D = 250 \ \mu Adc)$	V <sub>GS(th)</sub>	1.0	_	2.5	Vdc
On–State Drain Current $(V_{DS} \ge 2.0 V_{DS(on)}, V_{GS} = 10 \text{ Vdc})$	I <sub>D(on)</sub>	500	-	-	mA
Static Drain–Source On–State Voltage $(V_{GS} = 10 \text{ Vdc}, I_D = 500 \text{ mAdc})$ $(V_{GS} = 5.0 \text{ Vdc}, I_D = 50 \text{ mAdc})$	V <sub>DS(on)</sub>	-		3.75 0.375	Vdc
Static Drain–Source On–State Resistance $(V_{GS} = 10 \text{ V}, \text{ I}_D = 500 \text{ mAdc})$ $T_C = 25^{\circ}C$ $T_C = 125^{\circ}C$ $T_C = 125^{\circ}C$	r <sub>DS(on)</sub>	-		7.5 13.5 7.5	Ohms
$  (V_{GS} = 5.0 \text{ Vdc}, I_D = 50 \text{ mAdc}) \qquad \qquad \tilde{T}_C = 25^{\circ}C \\ T_C = 125^{\circ}C $		-	_	7.5 13.5	
Forward Transconductance $(V_{DS} \ge 2.0 V_{DS(on)}, I_D = 200 \text{ mAdc})$	9FS	80	-	-	mS
DYNAMIC CHARACTERISTICS					
Input Capacitance (V <sub>DS</sub> = 25 Vdc, V <sub>GS</sub> = 0, f = 1.0 MHz)	C <sub>iss</sub>	-	_	50	pF
Output Capacitance $(V_{DS} = 25 \text{ Vdc}, V_{GS} = 0, f = 1.0 \text{ MHz})$	C <sub>oss</sub>	-	-	25	pF
Reverse Transfer Capacitance $(V_{DS} = 25 \text{ Vdc}, V_{GS} = 0, f = 1.0 \text{ MHz})$	C <sub>rss</sub>	-	-	5.0	pF
SWITCHING CHARACTERISTICS (Note 5)			•		
Turn–On Delay Time $(V_{DD} = 25 \text{ Vdc}, I_D \cong 500 \text{ mAdc},$	t <sub>d(on)</sub>	_	_	20	ns
Turn–Off Delay Time $R_G = 25 \Omega$ , $R_L = 50 \Omega$ , $V_{gen} = 10 V$ )	t <sub>d(off)</sub>	-	_	40	ns
BODY-DRAIN DIODE RATINGS					
Diode Forward On–Voltage $(I_S = 115 \text{ mAdc}, V_{GS} = 0 \text{ V})$	$V_{SD}$	-	_	-1.5	Vdc
Source Current Continuous (Body Diode)	I <sub>S</sub>	-	-	-115	mAdc
Source Current Pulsed	I <sub>SM</sub>	_	_	- 800	mAdc

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions. 5. Pulse Test: Pulse Width  $\leq$  300 µs, Duty Cycle  $\leq$  2.0%.

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## **TYPICAL ELECTRICAL CHARACTERISTICS**



Drain-Source On-Resistance

**Threshold Voltage** 





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